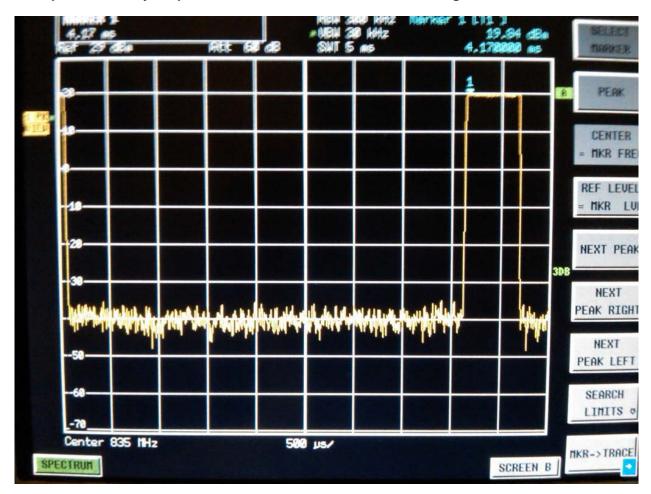
Testing Services™	Annex A to Hearing Air Report for the BlackBe REN71UW	Page 1 (342)		
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	- · · · · · · · · · · · · · · · · · · ·	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

Annex A: Measurement data and plots

A.1 Spectrum analyser plots: GSM/WCDMA, CW and 80%AM signals



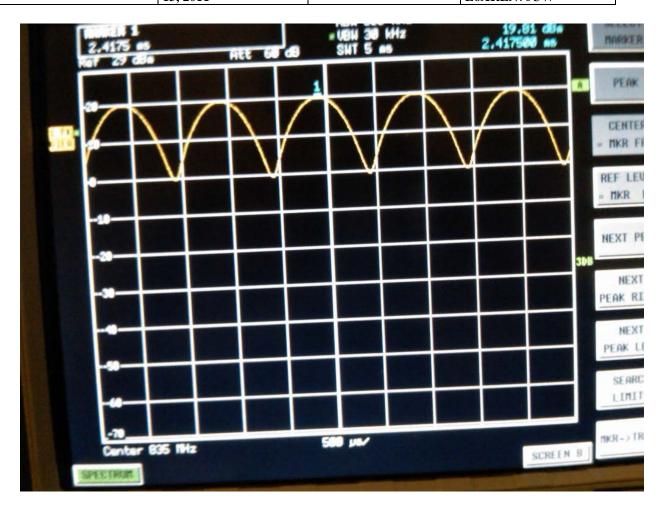
0 Hz Span GSM Plot (835MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 2 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13. 2011		L6AREN70U	W



0 Hz Span CDMA Plot (835MHz)

Testing Services	6 _	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/			
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW		J W		
	13, 2011		L6AREN70U	W	



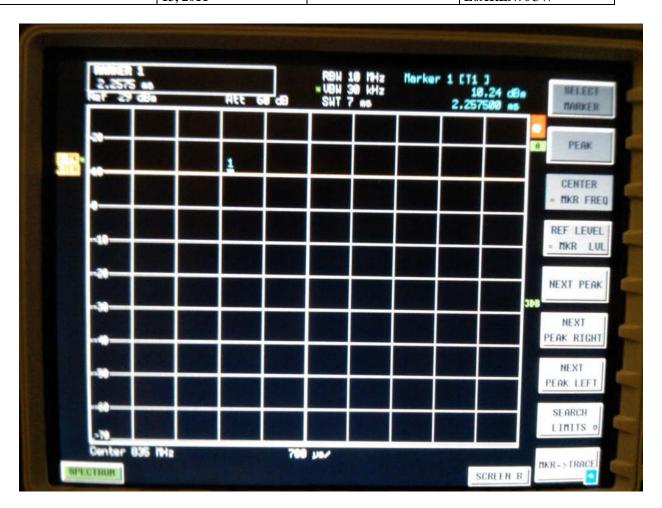
0 Hz Span AM 80% (835MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 4 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W



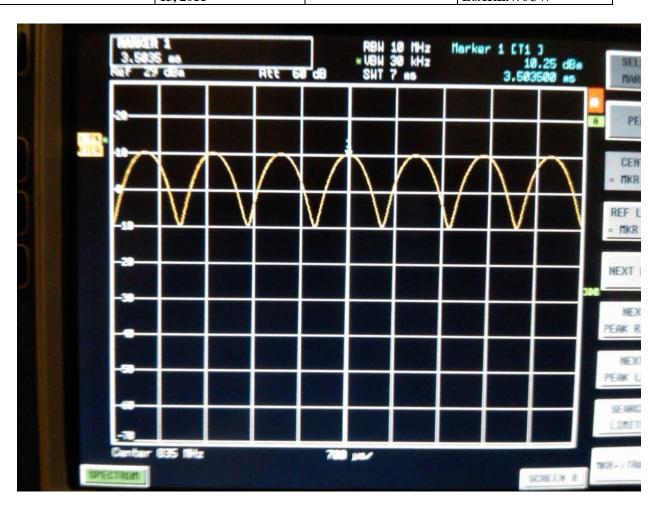
0 Hz Span WCDMA Plot (835MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 5 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W



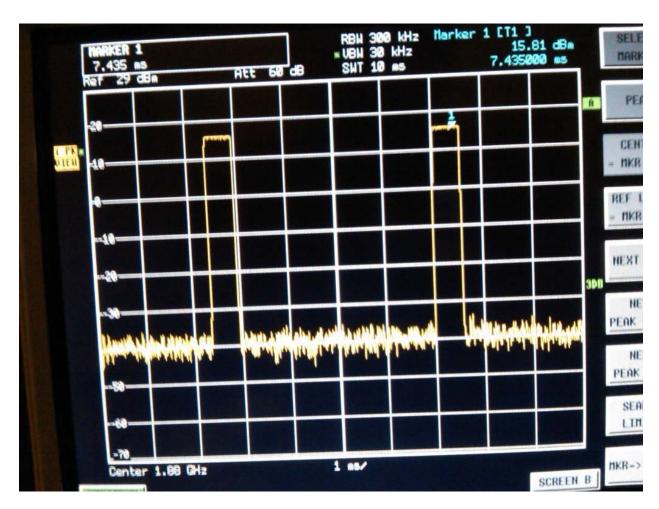
0 Hz Span CW Plot (835MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 6 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W



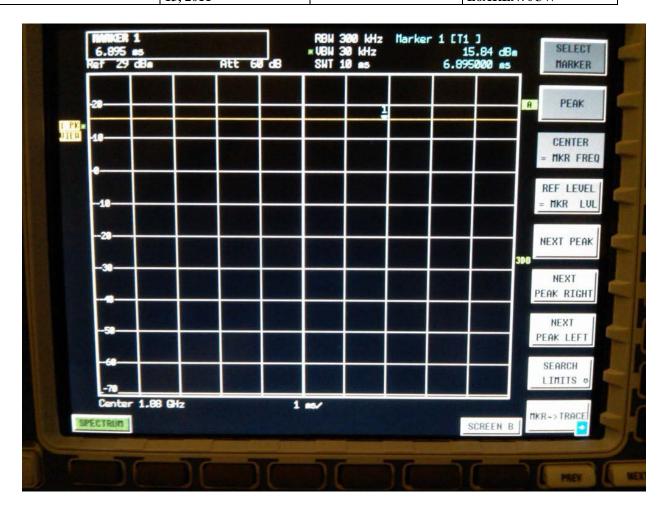
0 Hz Span AM80% (835MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 7 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	W



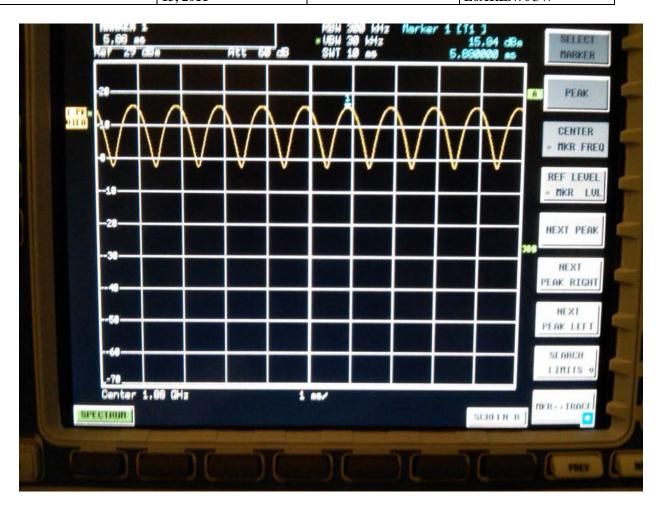
0 Hz Span GSM Plot (1880MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 8 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W



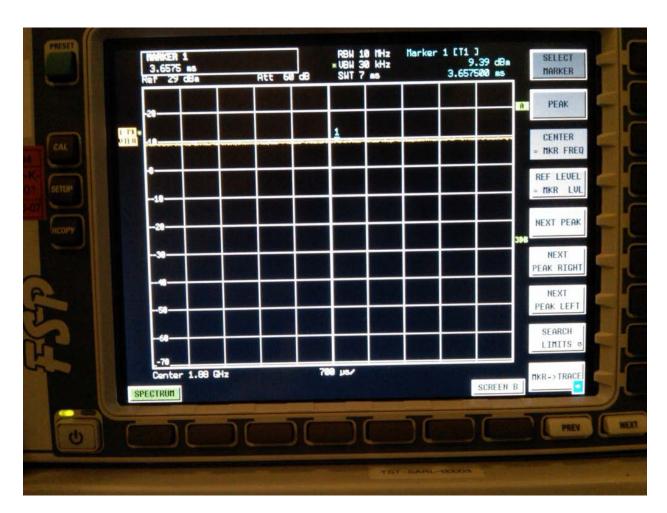
0 Hz Span CW Plot (1880MHz)

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70UW	
	13, 2011		L6AREN70U	\mathbf{W}



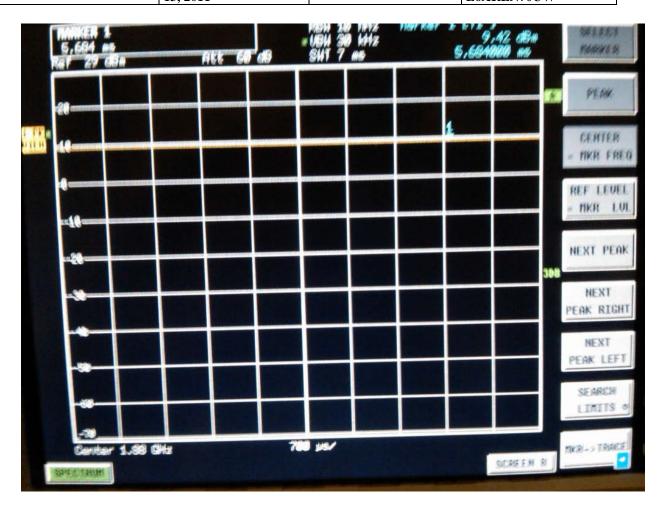
0 Hz Span AM80% (1880MHz)

Testing Services	·	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/			
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW		J W	
	13, 2011		L6AREN70U	W	



0 Hz Span WCDMA II Plot (1880MHz)

Author Data	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Dates of Test Report No Report No Record No			11 (342)
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			\mathbf{W}
	13, 2011		L6AREN70U	\mathbf{W}



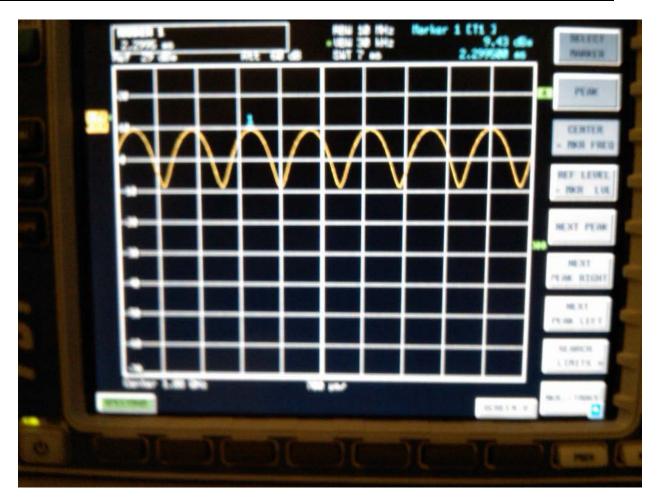
0 Hz Span CW Plot (1880MHz)



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12 (342)

FCC ID Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW 13, 2011 L6AREN70UW



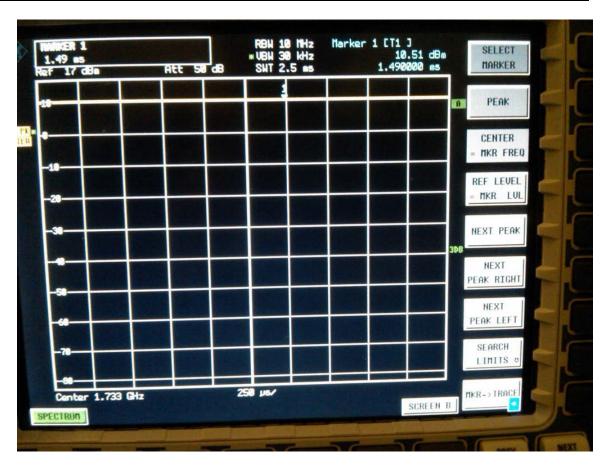
0 Hz Span AM80% (1880MHz)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/REN71UW			Page 13 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			\mathbf{W}
	13, 2011		L6AREN70U	W



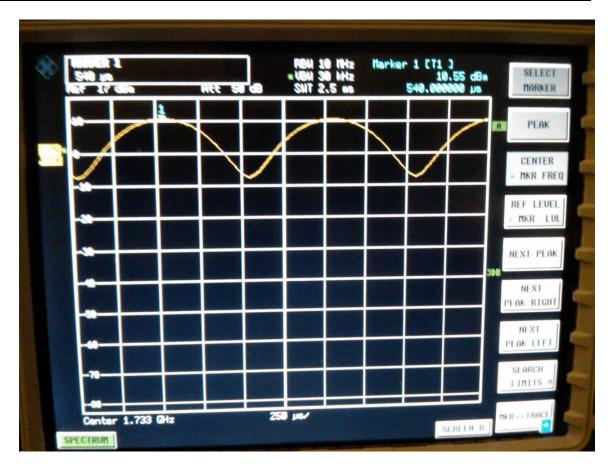
0 Hz Span WCDMA IV Plot (1733 MHz)

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	${}^{\mathrm{J}}\mathbf{W}$		
	13, 2011	W		



0 Hz Span CW (1733 MHz)

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	\mathbf{W}		
	13, 2011	W		



0 Hz Span AM 80% (1733 MHz)

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	\mathbf{W}

A.2 Dipole validation and probe modulation factor plots

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	\mathbf{W}		
	13, 2011	W		

Date/Time: 1/12/2011 12:39:57 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x37x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 110.5 V/m; Power Drift = -0.014 dB

Maximum value of Total (measured) = 168.0 V/m

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Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70			J W	
	13, 2011	F 1)-1 (

dx=5mm, dy=5mm

Maximum value of peak Total field = 169.7 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 110.5 V/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 2	Grid 3
169.7 M4	169.7 M4
Grid 5	Grid 6
84.9 M4	85.0 M4
Grid 8	Grid 9
166.2 M4	166.5 M4
	169.7 M4 Grid 5 84.9 M4 Grid 8

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 169.7 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 1:04:20 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: GSM 850; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.6 V/m; Power Drift = -0.001 dB

Maximum value of Total (measured) = 42.5 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	\mathbf{W}		
	13, 2011	\mathbf{W}		

dx=5mm, dy=5mm

Maximum value of peak Total field = 42.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.6 V/m; Power Drift = -0.001 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
39.9 M4	40.9 M4	39.0 M4
Grid 4	Grid 5	Grid 6
41 1 3 7 4	40 (3.54	41 1 3 7 4
41.1 M4	42.6 M4	41.1 M4
41.1 M4 Grid 7	42.6 N14 Grid 8	41.1 M4 Grid 9

Testing Services™		id Compatibility RF Em erry® Smartphone mod		Page 22 (342)
hor Data ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 23 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	$^{\mathrm{J}}\mathbf{W}$		
	13, 2011	\mathbf{W}		

Date/Time: 1/12/2011 12:52:38 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_CW_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: Omm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.8 V/m; Power Drift = -0.095 dB

Maximum value of Total (measured) = 127.7 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			
	13, 2011		L6AREN70U	\mathbf{W}

dx=5mm, dy=5mm

Maximum value of peak Total field = 128.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 103.8 V/m; Power Drift = -0.095 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
119.1 M4	122.8 M4	118.9 M4
Grid 4	Grid 5	Grid 6
122.2 M4	128.0 M4	124.4 M4
Grid 7	Grid 8	Grid 9
121.1 M4	127.8 M4	124.6 M4

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 128.0 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011	\mathbf{W}		

Date/Time: 1/12/2011 1:00:12 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_AM80%_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 63.6 V/m; Power Drift = 0.052 dB

Maximum value of Total (measured) = 79.5 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70			${ m J}{f W}$
	13, 2011	\mathbf{W}		

dx=5mm, dy=5mm

Maximum value of peak Total field = 80.1 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 63.6 V/m; Power Drift = 0.052 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
74.1 M4	76.6 M4	74.3 M4
Grid 4	Grid 5	Grid 6
76.1 M4	80.1 M4	77.6 M4
Grid 7	Grid 8	Grid 9
75.3 M4	79.2 M4	77.6 M4

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ndrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

 $0\ dB=80.1V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			$^{\mathrm{J}}\mathbf{W}$	
	13, 2011	, 1 , 5			

Date/Time: 1/12/2011 2:19:32 PM

Test Laboratory: RIM Testing Services HAC_E_Dipole_835MHz_WCDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: WCDMA FDD V; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 36.2 V/m; Power Drift = -0.048 dB

Maximum value of Total (measured) = 44.2 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	J W		
	13, 2011		L6AREN70U	\mathbf{W}

dx=5mm, dy=5mm

Maximum value of peak Total field = 44.5 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 36.2 V/m; Power Drift = -0.048 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
41.1 M4	43.0 M4	41.9 M4
Grid 4	Grid 5	Grid 6
42.2 M4	44.5 M4	43.9 M4
Grid 7	Grid 8	Grid 9
41.6 M4	44.3 M4	43.9 M4

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	REPORT NO RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

 $0\;dB=44.5V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 1:59:34 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_CW_WCDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1 Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 35.4 V/m; Power Drift = -0.025 dB

Maximum value of Total (measured) = 42.1 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 33 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

dx=5mm, dy=5mm

Maximum value of peak Total field = 42.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 35.4 V/m; Power Drift = -0.025 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
38.5 M4	41.1 M4	40.8 M4
Grid 4	Grid 5	Grid 6
39.5 M4	42.8 M4	42.7 M4
Grid 7	Grid 8	Grid 9
39.2 M4	42.8 M4	42.7 M4

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

 $0\ dB=42.8V/m$

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 2:06:22 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_835MHz_AM80%_WCDMA

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD835

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.6 V/m; Power Drift = -0.033 dB

Maximum value of Total (measured) = 26.8 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

dx=5mm, dy=5mm

Maximum value of peak Total field = 27.2 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.6 V/m; Power Drift = -0.033 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
24.5 M4	26.2 M4	26.0 M4
Grid 4	Grid 5	Grid 6
25.1 M4	27.2 M4	27.1 M4
Grid 7	Grid 8	Grid 9
24.9 M4	27.2 M4	27.1 M4

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Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U		

 $0\;dB=27.2V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 2:35:41 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm/Hearing Aid Compatibility Test (5x19x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 128.4 V/m; Power Drift = -0.030 dB

Maximum value of Total (measured) = 126.3 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 127.8 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 128.4 V/m; Power Drift = -0.030 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
109.1 M3	127.8 M2	127.8 M2
Grid 4	Grid 5	Grid 6
68.3 M3	75.8 M3	75.8 M3
Grid 7	Grid 8	Grid 9
106.5 M3	123.0 M2	123.0 M2

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

0 dB = 127.8V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 2:55:50 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 28.5 V/m; Power Drift = -0.028 dB

Maximum value of Total (measured) = 23.2 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 23.3 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 28.5 V/m; Power Drift = -0.028 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
21.8 M4	22.6 M4	21.8 M4
Grid 4	Grid 5	Grid 6
22.2 M4	23.3 M4	22.6 M4
Grid 7	Grid 8	Grid 9
21.7 M4	22.7 M4	22.2 M4

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Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 2:41:36 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_CW_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 5/17/2010
- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 73.4 V/m; Power Drift = 0.047 dB

Maximum value of Total (measured) = 60.8 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
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Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 60.9 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 73.4 V/m; Power Drift = 0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
57.6 M4	59.9 M4	57.3 M4
Grid 4	Grid 5	Grid 6
58.4 M4	60.9 M4	58.9 M4
Grid 7	Grid 8	Grid 9
56.6 M4	59.5 M4	57.8 M4

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Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

0 dB = 60.9 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 2:45:33 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_AM80%_GSM

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 46.8 V/m; Power Drift = 0.052 dB

Maximum value of Total (measured) = 38.6 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 38.6 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 46.8 V/m; Power Drift = 0.052 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
36.5 M4	37.9 M4	36.6 M4
Grid 4	Grid 5	Grid 6
37.1 M4	38.6 M4	37.5 M4
Grid 7	Grid 8	Grid 9
36.1 M4	37.7 M4	36.9 M4

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

0 dB = 38.6 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:05:57 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_WCDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 39.2 V/m; Power Drift = -0.172 dB

Maximum value of Total (measured) = 31.3 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 31.4 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 39.2 V/m; Power Drift = -0.172 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
29.6 M4	30.8 M4	30.0 M4
Grid 4	Grid 5	Grid 6
30.1 M4	31.4 M4	30.9 M4
Grid 7	Grid 8	Grid 9
29.4 M4	31.1 M4	30.5 M4

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 31.4V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 2:51:24 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_CW_WCDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.7 V/m; Power Drift = -0.060 dB

Maximum value of Total (measured) = 28.3 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 28.3 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 34.7 V/m; Power Drift = -0.060 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
26.9 M4	27.8 M4	27.1 M4
Grid 4	Grid 5	Grid 6
27.4 M4	28.3 M4	27.6 M4
Grid 7	Grid 8	Grid 9
26.5 M4	27.7 M4	27.3 M4

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thor Data ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM700			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 2:48:40 PM

Test Laboratory: RIM Testing Services

HAC_E_Dipole_1880MHz_AM80%_WCDMA

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - measurement distance from the probe sensor center to CD1880

Dipole = 10mm 2/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.1 V/m; Power Drift = 0.021 dB

Maximum value of Total (measured) = 18.0 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm 2/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 18.0 V/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.1 V/m; Power Drift = 0.021 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
17.0 M4	17.7 M4	17.1 M4
Grid 4	Grid 5	Grid 6
17.3 M4	18.0 M4	17.6 M4
Grid 7	Grid 8	Grid 9
16.8 M4	17.6 M4	17.4 M4

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0~dB=18.0V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM700			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:55:25 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho_r = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.497 A/m; Power Drift = -0.014 dB

Maximum value of Total (measured) = 0.466 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.467 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.497 A/m; Power Drift = -0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.437 M4	0.450 M4	0.432 M4
Grid 4	Grid 5	Grid 6
0.450 M4	0.467 M4	0.444 M4
Grid 7	Grid 8	Grid 9

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 61 (342)			
uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

0 dB = 0.467 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 62 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 4:23:11 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: GSM 850; Frequency: 835 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.162 A/m; Power Drift = -0.057 dB

Maximum value of Total (measured) = 0.153 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.153 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.162 A/m; Power Drift = -0.057 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.139 M4	0.145 M4	0.138 M4
Grid 4	Grid 5	Grid 6
0.145 M4	0.153 M4	0.145 M4
Grid 7	Grid 8	Grid 9
0.145 M4	0.153 M4	0.143 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 64 (342)	
ndrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

0 dB = 0.153 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 65 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	$^{\mathrm{J}}\mathbf{W}$
	13. 2011		L6AREN70U	W

Date/Time: 1/12/2011 4:05:24 PM

Test Laboratory: RIM Testing Services
HAC_H_Dipole_835MHz_CW_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.466 A/m; Power Drift = -0.033 dB

Maximum value of Total (measured) = 0.439 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 66 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.439 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.466 A/m; Power Drift = -0.033 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.412 M4	0.427 M4	0.413 M4
Grid 4	Grid 5	Grid 6
0.423 M4	0.439 M4	0.419 M4
Grid 7	Grid 8	Grid 9
0.423 M4	0.438 M4	0.419 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 67 (342)			
uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

0 dB = 0.439 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 68 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

Date/Time: 10/25/2010 5:26:25 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_AM80%_GSM_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3

Communication System: AM 80%

Frequency: 835 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/13/2009

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn473; Calibrated: 1/4/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, Version 4.7 (80); SEMCAD X Version 14.4.4 (2829)

Configuration/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x121x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.263 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.280 A/m; Power Drift = -0.07 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.249 M4	0.256 M4	0.244 M4
Grid 4	Grid 5	Grid 6
0.252 M4	0.263 M4	0.250 M4
Grid 7	Grid 8	Grid 9
0.252 M4	0.262 M4	0.249 M4

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uthor Data	Dates of Test	Report No	FCC ID	7887	
andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U		
	13, 2011		L6AREN70U	W	

0 dB = 0.260 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM700			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 4:42:42 PM

Test Laboratory: RIM Testing Services HAC_H_Dipole_835MHz_WCDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: WCDMA FDD V; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: Omm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.157 A/m; Power Drift = -0.007 dB

Maximum value of Total (measured) = 0.149 A/m

Testing Services Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 72 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.149 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.157 A/m; Power Drift = -0.007 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.138 M4	0.143 M4	0.139 M4
Grid 4	Grid 5	Grid 6
0.144 M4	0.149 M4	0.144 M4
Grid 7	Grid 8	Grid 9
0.144 M4	0.149 M4	0.142 M4

lesting Services™	Annex A to Hearing A Report for the BlackB REN71UW	id Compatibility RF Em erry® Smartphone mod	issions Test lel RDM71UW/	Page 73 (342)
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

0 dB = 0.149 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 74 (342)
Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 4:11:32 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_CW_WCDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: CW; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.154 A/m; Power Drift = -0.047 dB

Maximum value of Total (measured) = 0.146 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 75 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.146 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.154 A/m; Power Drift = -0.047 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.137 M4	0.142 M4	0.137 M4
Grid 4	Grid 5	Grid 6
0.141 M4	0.146 M4	0.140 M4
Grid 7	Grid 8	Grid 9
0.142 M4	0.146 M4	0.139 M4

uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	FCC ID	
	,		L6ARDM70U L6AREN70U	

0 dB = 0.146 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 77 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 4:15:42 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_835MHz_AM80%_WCDMA_mod

DUT: HAC-Dipole 835 MHz; Type: D835V3;

Communication System: AM 80%; Frequency: 835 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (5x9x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.099 A/m; Power Drift = -0.003 dB

Maximum value of Total (measured) = 0.093 A/m

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 78 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			J W
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x81x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.094 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.099 A/m; Power Drift = -0.003 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.088 M4	0.091 M4	0.088 M4
Grid 4	Grid 5	Grid 6
0.090 M4	0.093 M4	0.089 M4
Grid 7	Grid 8	Grid 9

Testing Services™		id Compatibility RF Em erry® Smartphone mod		Page 79 (342)	
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 0.094 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 80 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 2:49:30 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x11x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.478 A/m; Power Drift = 0.007 dB

Maximum value of Total (measured) = 0.449 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x101x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.450 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.478 A/m; Power Drift = 0.007 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.416 M2	0.432 M2	0.413 M2
Grid 4	Grid 5	Grid 6
0.433 M2	0.450 M2	0.430 M2
Grid 7	Grid 8	Grid 9
0.425 M2	0.444 M2	0.422 M2

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 82 (342)			
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

0~dB=0.450A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:23:31 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.091 A/m; Power Drift = 0.116 dB

Maximum value of Total (measured) = 0.085 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.086 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.091 A/m; Power Drift = 0.116 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Grid 1	Grid 2	Grid 3
0.081 M4	0.085 M4	0.081 M4
Grid 4	Grid 5	Grid 6
0.082 M4	0.086 M4	0.082 M4
Grid 7	Grid 8	Grid 9
0.082 M4	0.086 M4	0.082 M4

Testing Services™	Annex A to Hearing Ai Report for the BlackBe REN71UW	id Compatibility RF Emi erry® Smartphone mode	ssions Test el RDM71UW/	Page 85 (342)
author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

0 dB = 0.086 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 86 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:32:55 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_CW_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.250 A/m; Power Drift = 0.055 dB

Maximum value of Total (measured) = 0.236 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 87 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.237 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.250 A/m; Power Drift = 0.055 dB

Hearing Aid Near-Field Category: M3 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.227 M3	0.235 M3	0.228 M3
Grid 4	Grid 5	Grid 6
0.229 M3	0.237 M3	0.230 M3
Grid 7	Grid 8	Grid 9
0.229 M3	0.237 M3	0.229 M3

0 dB = 0.237 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:36:08 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_AM80%_GSM_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.163 A/m; Power Drift = -0.022 dB

Maximum value of Total (measured) = 0.153 A/m

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	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.154 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.163 A/m; Power Drift = -0.022 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.148 M4	0.152 M4	0.147 M4
Grid 4	Grid 5	Grid 6
0.150 M4	0.154 M4	0.148 M4
Grid 7	Grid 8	Grid 9
0.150 M4	0.154 M4	0.148 M4

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:20:17 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_WCDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.139 A/m; Power Drift = -0.064 dB

Maximum value of Total (measured) = 0.130 A/m

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	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.131 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.139 A/m; Power Drift = -0.064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.124 M4	0.129 M4	0.125 M4
Grid 4	Grid 5	Grid 6
0.126 M4	0.131 M4	0.126 M4
Grid 7	Grid 8	Grid 9
0.126 M4	0.131 M4	0.126 M4

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 94 (342)			
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0 dB = 0.131 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 3:41:59 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_CW_WCDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.121 A/m; Power Drift = 0.104 dB

Maximum value of Total (measured) = 0.115 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.116 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.121 A/m; Power Drift = 0.104 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.111 M4	0.115 M4	0.112 M4
Grid 4	Grid 5	Grid 6
0.113 M4	0.116 M4	0.112 M4
Grid 7	Grid 8	Grid 9
0.113 M4	0.116 M4	0.112 M4

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
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0 dB = 0.116A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 3:38:32 PM

Test Laboratory: RIM Testing Services

HAC_H_Dipole_1880MHz_AM80%_WCDMA_mod

DUT: HAC Dipole 1880 MHz; Type: CD1880V3;

Communication System: AM 80%; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (5x5x1): Measurement grid:

dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.080 A/m; Power Drift = 0.010 dB

Maximum value of Total (measured) = 0.075 A/m

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Dipole = 10mm/Hearing Aid Compatibility Test (41x41x1): Measurement grid:

dx=5mm, dy=5mm

Maximum value of peak Total field = 0.075 A/m

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.080 A/m; Power Drift = 0.010 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.072 M4	0.074 M4	0.072 M4
Grid 4	Grid 5	Grid 6
0.073 M4	0.075 M4	0.073 M4
Grid 7	Grid 8	Grid 9
0.073 M4	0.075 M4	0.072 M4

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

 $0\ dB=0.075A/m$

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

Date/Time: 4/5/2011 3:15:31 PM, Date/Time: 4/5/2011 3:35:37 PM, Date/Time:

4/5/2011 3:50:05 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_1733 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD IV, Communication System: CW,

Communication System: AM80%; Communication System Band: 1733; Frequency:

1732.6 MHz, Frequency: 1733 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn473; Calibrated: 1/21/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility

Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.953 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	\mathbf{W}

Reference Value = 45.671 V/m; Power Drift = 0.0022 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
44.309	45.897	43.942
M4	M4	M4
Grid 4	Grid 5	Grid 6
32.194	33.381	32.650
M4	M4	M4
Grid 7	Grid 8	Grid 9
45.541	45.953	44.163
M4	M4	M4

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 44.684 V/m

Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 44.777 V/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
42.576	44.154	42.558
M4	M4	M4
Grid 4	Grid 5	Grid 6
31.220	32.494	31.749
M4	M4	M4
Grid 7	Grid 8	Grid 9
44.140	44.684	42.994
M4	M4	M4

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2 2/Hearing Aid

Compatibility Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28.697 V/m

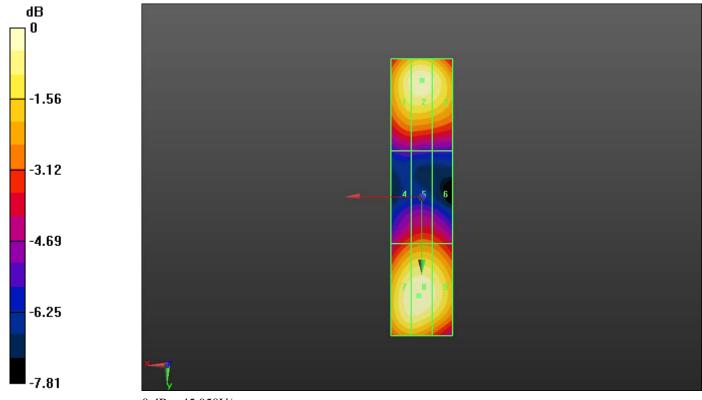
Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 28.666 V/m; Power Drift = -0.03 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
27.579	28.576	27.503
M4	M4	M4
Grid 4	Grid 5	Grid 6
20.034	20.866	20.402
M4	M4	M4
Grid 7	Grid 8	Grid 9
28.387	28.697	27.712
M4	M4	M4

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0 dB = 45.950 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

Date/Time: 7/11/2011 11:41:33 AM

Test Laboratory: RIM Testing Services HAC RF_E-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz);

Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole E-Field measurement/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility

Test (41x181x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 132.4 V/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 122.0 V/m; Power Drift = -0.01 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	\mathbf{W}

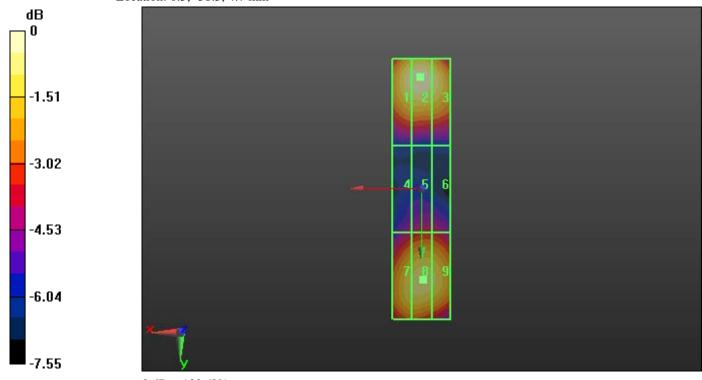
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
128.6	132.4	125.9
M2	M2	M2
Grid 4	Grid 5	Grid 6
82.565	87.292	86.553
M3	M3	M3
Grid 7	Grid 8	Grid 9
119.4	122.5	120.6
M2	M2	M2

Cursor:

Total = 132.4 V/m E Category: M2

Location: 0.5, -38.5, 4.7 mm



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	13, 2011		L6AREN70U	W

Date/Time: 4/5/2011 4:22:30 PM, Date/Time: 4/5/2011 4:37:10 PM, Date/Time:

4/5/2011 4:40:56 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_1733 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: WCDMA FDD IV, Communication System: CW,

Communication System: AM80%; Communication System Band: D1800 (1800.0 MHz);

Frequency: 1732.6 MHz, Frequency: 1733 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn473; Calibrated: 1/21/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility

Test (41x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.165 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

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Reference Value = 0.175 A/m; Power Drift = -0.0064 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.148	0.156	0.151
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.156	0.165	0.159
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.151	0.160	0.153
M4	M4	M4

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.160 A/m

Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.172 A/m; Power Drift = -0.08 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.144	0.151	0.147
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.152	0.160	0.155
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.148	0.156	0.149
M4	M4	M4

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	13, 2011		L6AREN70U	W

Dipole H-Field with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm 2 2/Hearing Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm,

dy=5mm

Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

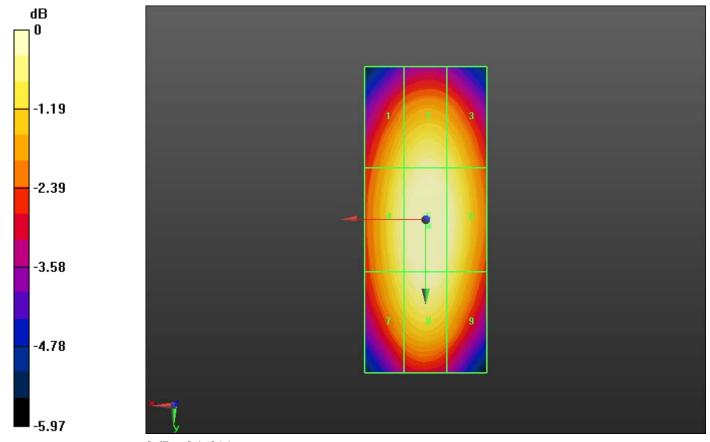
Reference Value = 0.110 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.091	0.097	0.093
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.096	0.102	0.098
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.093	0.099	0.094
M4	M4	M4

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	13, 2011		L6AREN70U	\mathbf{W}



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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 7/11/2011 2:34:34 PM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_validation_1880 MHz

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Communication System Band: D1900 (1900.0 MHz);

Frequency: 1880 MHz; Communication System PAR: 0 dB

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY5 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY52, Version 52.6 (2); SEMCAD X Version 14.4.4 (2829)

Dipole H-Field meausrement with H3DV6 probe/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing

Aid Compatibility Test (41x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.461 A/m

Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.490 A/m; Power Drift = 0.02 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

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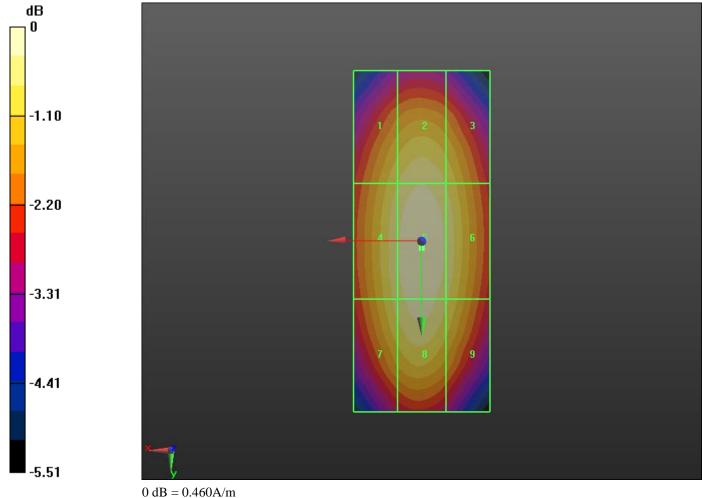
Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.423	0.441	0.423
M2	M2	M2
Grid 4	Grid 5	Grid 6
0.439	0.461	0.439
M2	M2	M2
Grid 7	Grid 8	Grid 9
0.432	0.453	0.428
M2	M2	M2

Cursor:

Total = 0.461 A/m H Category: M2 Location: 0, 1, 4.7 mm

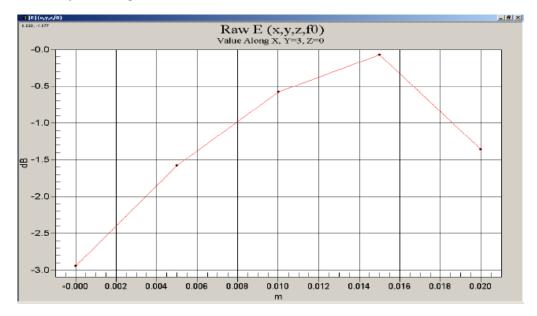
Testing Services™	_	d Compatibility RF Emiserry® Smartphone model		Page 113 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
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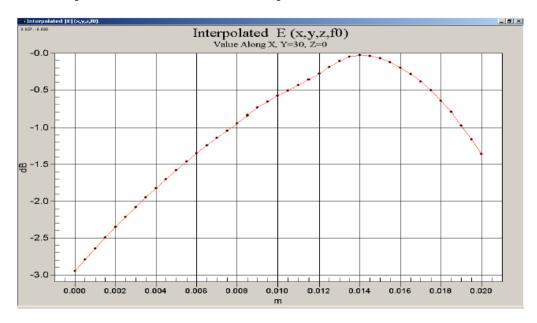
Testing Services™		id Compatibility RF Emis erry® Smartphone mode		Page 114 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

Justification of Step Size and Interpolation

This section demonstrates that a 5mm step size with interpolation provides sufficient resolution for RF emissions measurements. The DASY 4 uses interpolation algorithms to derive 9 interpolated points between every measured point.

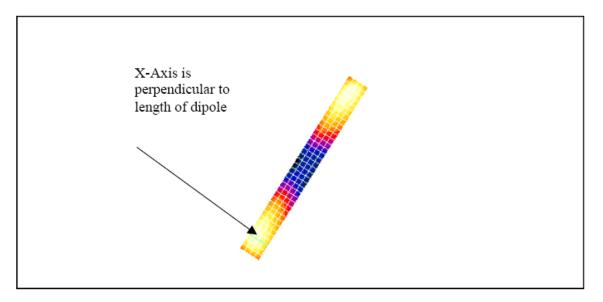


The figure above shows the raw measured field strength perpendicular to the length of the validation dipole. The TCB guidance slides require the 3dB width to be much larger than the step size. The width between -3dB points is ≥ 21 mm, at least 4 times the step size.



This figure shows the interpolated field strength perpendicular to the dipole. The interpolated points follow the raw points with no inconsistencies.

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The green line in this figure shows the axis along which the points lie.

Comparison of 5mm and 2mm step sizes

An additional set of measurements was taken: dipole validations were performed using 5mm and 2mm step sizes. The delta between the two readings is insignificant for both field types (< 0.4% for E and 0% for H), demonstrating that 5mm is sufficient. The plots follow.

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Date/Time: 14/07/2005 11:35:24 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 134.8 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total field (slot averaged) = 131.0 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.2					138.4
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
80.9	92.3	92.2	80.9	92.3	92.2
Grid 7			Grid 7	Grid 8	Grid 9
119.8	131.0	130.7	119.8	131.0	130.7

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
М3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
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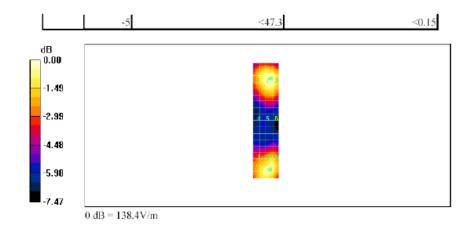
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Date/Time: 14/07/2005 11:44:51 AM

Lab: RIM Testing Services (RTS)

Dipole Validation 1880 MHz_2mm step_E-Field 07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz; Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: H Device Section

DASY4 Configuration:

- Probe: ER3DV6 SN2285; ConvF(1, 1, 1); Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 138.0 V/m

E Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total field (slot averaged) = 131.2 V/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

E in V/m (Time averaged) E in V/m (Slot averaged)

				-	-
Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
123.1	138.6	138.6	123.1	138.6	138.6
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
81.4	92.1	91.6	81.4	92.1	91.6
Grid 7			Grid 7		
121.3	131.2	131.0	121.3	131.2	131.0

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
М3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
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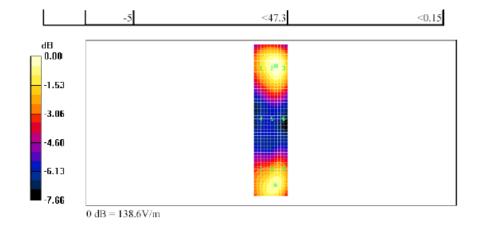
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Date/Time: 14/07/2005 12:43:02 PM

Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_5 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma=0$ mho/m, $\epsilon_r=1$; $\rho=1$ kg/m³

Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 10/12/2004

- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (5x19x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of Total field (slot averaged) = 0.406 A/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

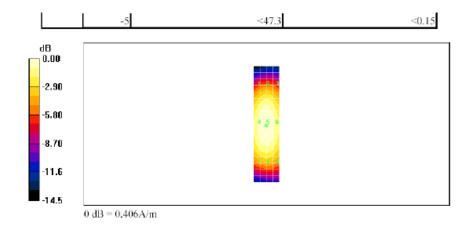
Grid 1	Grid 2	Grid 3		Grid 1	Grid 2	Grid 3
0.342	0.359	0.344		0.342	0.359	0.344
Grid 4				Grid 4		
0.389	0.406	0.389		0.389	0.406	0.389
Grid 7				Grid 7		
0.363	0.378	0.363		0.363	0.378	0.363

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
М3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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Lab: RIM Testing Services (RTS)

HAC_H_Dipole_CW 1880_2 mm step_07_14_05

DUT: HAC Dipole 1880 MHz; Type: CD1880V3

Communication System: CW; Frequency: 1880 MHz;Duty Cycle: 1:1 Medium: Air Medium parameters used: $\sigma = 0$ mho/m, $\varepsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: H Dipole Section

DASY4 Configuration:

- Probe: H3DV6 SN6105; ; Calibrated: 10/12/2004
- Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn472; Calibrated: 03/01/2005
- Phantom: HAC Test Arch; Type: SD HAC P01 BA;
- Measurement SW: DASY4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (11x46x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total (measured) = 0.406 A/m

H Scan 10mm above CD 1880 MHz/Hearing Aid Compatibility Test (101x451x1):

Measurement grid: dx=2mm, dy=2mm

Maximum value of Total field (slot averaged) = 0.406 A/m

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

H in A/m (Time averaged) H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid
0.347	0.361	0.348	0.347	0.361	0.34
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid
0.394	0.406	0.391	0.394	0.406	0.39
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid
0.367	0.380	0.365	0.367	0.380	0.36

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
М3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19

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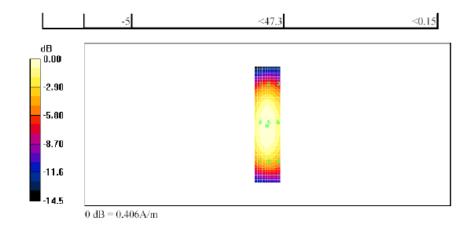
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A.3 RF emissions plots

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	13, 2011		L6AREN70U	\mathbf{W}	

Date/Time: 1/13/2011 3:24:09 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 60.9 V/m; Power Drift = -0.144 dB

Maximum value of Total (measured) = 49.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Maximum value of peak Total field = 150.2 V/m

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 60.9 V/m; Power Drift = -0.144 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
129.6 M4	146.3 M4	146.2 M4
Grid 4	Grid 5	Grid 6
133.0 M4	150.2 M3	150.2 M3
Grid 7	Grid 8	Grid 9
132.2 M4	148.4 M4	148.4 M4

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0 dB = 150.2 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			\mathbf{W}	
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Date/Time: 1/13/2011 3:30:17 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 71.3 V/m; Power Drift = 0.066 dB

Maximum value of Total (measured) = 61.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U		

Maximum value of peak Total field = 184.0 V/m

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 71.3 V/m; Power Drift = 0.066 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
149.8 M3	178.1 M3	177.9 M3
Grid 4	Grid 5	Grid 6
153.3 M3	184.0 M3	184.0 M3
Grid 7	Grid 8	Grid 9
155.1 M3	183.5 M3	183.5 M3

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0 dB = 184.0 V/m

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	13, 2011		L6AREN70U	W

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Test Laboratory: RIM Testing Services

HAC_E_GSM850_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 77.0 V/m; Power Drift = -0.133 dB

Maximum value of Total (measured) = 64.8 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		LL6AREN70U	W

Maximum value of peak Total field = 195.1 V/m

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 77.0 V/m; Power Drift = -0.133 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
164.5 M3	193.0 M3	193.0 M3
Grid 4	Grid 5	Grid 6
163.7 M3	195.1 M3	195.1 M3
Grid 7	Grid 8	Grid 9
159.6 M3	192.0 M3	192.0 M3

lesting Services™	Report for the BlackB REN71UW	id Compatibility RF Em erry® Smartphone mod	del RDM71UW/	133 (342)
	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

0 dB = 195.1 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 134 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 3:47:50 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_high_chan_Telecoil

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY4 (High Precision Assessment)

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 76.3 V/m; Power Drift = -0.158 dB

Maximum value of Total (measured) = 63.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Maximum value of peak Total field = 190.6 V/m

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 76.3 V/m; Power Drift = -0.158 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
175.8 M3	182.9 M3	170.0 M3
Grid 4	Grid 5	Grid 6
175.8 M3	190.2 M3	184.3 M3
Grid 7	Grid 8	Grid 9
175.6 M3	190.6 M3	185.0 M3

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RTS-3640-1102-01B		
	Report No	1

0 dB = 190.6 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 12:11:39 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_low_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 61.5 V/m; Power Drift = -0.043 dB

Maximum value of Total (measured) = 49.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 47.2 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 61.5 V/m; Power Drift = -0.043 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
39.9 M4	46.4 M4	46.3 M4
Grid 4	Grid 5	Grid 6
40.8 M4	47.2 M4	46.9 M4
Grid 7	Grid 8	Grid 9
40.1 M4	46.6 M4	46.4 M4

Testing Services™	REN71UW			
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

 $0\;dB=47.2V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/REN71UW			Page 140 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 12:17:05 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_mid_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 62.8 V/m; Power Drift = -0.165 dB

Maximum value of Total (measured) = 50.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 48.8 V/m

Testing Services		Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/		
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 62.8 V/m; Power Drift = -0.165 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
39.1 M4	47.1 M4	47.1 M4
Grid 4	Grid 5	Grid 6
40.1 M4	48.8 M4	48.8 M4
Grid 7	Grid 8	Grid 9
40.6 M4	48.7 M4	48.5 M4

Testing Services™	REN/1UW				
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

 $0\ dB = 48.8V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/REN71UW			Page 143 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 12:22:07 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_high_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 69.5 V/m; Power Drift = 0.114 dB

Maximum value of Total (measured) = 64.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.4 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 144 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 69.5 V/m; Power Drift = 0.114 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
51.7 M4	55.0 M4	55.0 M4
Grid 4	Grid 5	Grid 6
46.3 M4	60.4 M4	61.7 M4
Grid 7	Grid 8	Grid 9
45.3 M4	60.0 M4	54.3 M4

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 145 (342)				
thor Data ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70UW L6AREN70UW		

 $0\;dB=61.7V/m$

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 12:27:05 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_high_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 70.6 V/m; Power Drift = -0.034 dB

Maximum value of Total (measured) = 63.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 60.4 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		LL6AREN70U	W

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 70.6 V/m; Power Drift = -0.034 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
48.6 M4	51.3 M4	47.3 M4
Grid 4	Grid 5	Grid 6
55.2 M4	60.4 M4	52.3 M4
Grid 7	Grid 8	Grid 9
57.4 M4	61.0 M4	53.0 M4

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 $0\ dB=61.0V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			• •
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 5:20:58 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_low_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 13.6 V/m; Power Drift = -0.256 dB

Maximum value of Total (measured) = 33.9 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 77.6 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${\sf JW}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 13.6 V/m; Power Drift = -0.256 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
82.1 M3	88.5 M2	84.6 M2
Grid 4	Grid 5	Grid 6
41.8 M4	52.2 M3	53.3 M3
Grid 7	Grid 8	Grid 9
61.7 M3	77.6 M3	77.6 M3

Testing Services™	Report for the BlackB REN71UW	id Compatibility RF Em erry® Smartphone mod	issions Test el RDM71UW/	Page 151 (342)
Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

 $0\ dB=88.5V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 5:26:03 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_mid_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 16.1 V/m; Power Drift = -0.285 dB

Maximum value of Total (measured) = 32.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 63.4 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July	T			
	13, 2011		L6AREN70U	W	

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 16.1 V/m; Power Drift = -0.285 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
71.2 M3	83.7 M3	82.6 M3
Grid 4	Grid 5	Grid 6
39.4 M4	56.4 M3	57.6 M3
Grid 7	Grid 8	Grid 9
51.1 M3	63.4 M3	63.4 M3

Testing Services™	Report for the BlackB REN71UW	id Compatibility RF Emis erry® Smartphone mode		Page 154 (342)
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 $0\ dB=83.7V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
Author Data	Dates of Test Report No FCC ID				
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$	
	13, 2011				

Date/Time: 1/13/2011 5:31:00 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_high_chan

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 15.7 V/m; Power Drift = -0.174 dB

Maximum value of Total (measured) = 30.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 59.0 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 15.7 V/m; Power Drift = -0.174 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
61.2 M3	79.1 M3	79.0 M3
Grid 4	Grid 5	Grid 6
35.7 M4	56.9 M3	59.0 M3
Grid 7	Grid 8	Grid 9
39.4 M4	47.6 M3	47.6 M3

Testing Services™		id Compatibility RF Em erry® Smartphone mod		Page 157 (342)
Author Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

 $0\ dB = 79.1V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 5:37:55 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_low_chan_Telecoil

DUT: BlackBerry Smartphone

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 12.8 V/m; Power Drift = -0.080 dB

Maximum value of Total (measured) = 35.5 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 66.4 V/m

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Dates of Test Report No FCC ID			
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	Report for the BlackBe REN71UW Dates of Test Jan. 12-13, Apr 5, July	Annex A to Hearing Aid Compatibility RF Emis Report for the BlackBerry® Smartphone mode REN71UW Dates of Test Jan. 12-13, Apr 5, July RTS-3640-1102-01B	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Dates of Test Report No FCC ID

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 12.8 V/m; Power Drift = -0.080 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
92.8 M2	92.9 M2	78.0 M3
Grid 4	Grid 5	Grid 6
61.4 M3	66.4 M3	64.1 M3
Grid 7	Grid 8	Grid 9
52.1 M3	63.4 M3	63.3 M3

Testing Services™		id Compatibility RF Em erry® Smartphone mod		Page 160 (342)	
author Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U		

 $0\ dB = 92.9V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 161 (342)
Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			\mathbf{W}
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 12:40:26 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_low_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.2 V/m; Power Drift = -0.831 dB

Maximum value of Total (measured) = 37.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.6 V/m

Testing Services	Annex A to Hearing Air Report for the BlackB	Page 162 (342)		
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.2 V/m; Power Drift = -0.831 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
27.8 M4	33.4 M4	33.0 M4
Grid 4	Grid 5	Grid 6
14.6 M4	21.9 M4	25.1 M4
Grid 7	Grid 8	Grid 9
22.6 M4	31.6 M4	29.5 M4

Services™	REN71UW	erry® Smartphone mod		163 (342)
Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

 $0\;dB=33.4V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 164 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 12:50:24 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_mid_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 23.9 V/m; Power Drift = 0.122 dB

Maximum value of Total (measured) = 42.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 28.6 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 165 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${\sf J}{f W}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 23.9 V/m; Power Drift = 0.122 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
28.6 M4	38.0 M4	38.0 M4
Grid 4	Grid 5	Grid 6
15.8 M4	27.6 M4	28.7 M4
Grid 7	Grid 8	Grid 9
22.3 M4	27.2 M4	27.1 M4

lesting Service	REN71UW Dates of Test	Report No	FCC ID	166 (342)
ndrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	$_{ m JW}$
	13, 2011		L6AREN70U	
				_

 $0\ dB = 38.0 V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 167 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/13/2011 12:55:12 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_high_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.9 V/m; Power Drift = -0.487 dB

Maximum value of Total (measured) = 48.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.6 V/m

Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 168 (342)
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Jan. 12-13, Apr 5, July	RTS-3640-1102-01B		
	Annex A to Hearing Ai Report for the BlackBe REN71UW Dates of Test Jan. 12-13, Apr 5, July	Annex A to Hearing Aid Compatibility RF Em Report for the BlackBerry® Smartphone mod REN71UW Dates of Test Jan. 12-13, Apr 5, July RFS-3640-1102-01B	Report for the BlackBerry® Smartphone model RDM71UW/REN71UW Dates of Test Report No FCC ID

Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.9 V/m; Power Drift = -0.487 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
31.6 M4	43.5 M4	42.4 M4
Grid 4	Grid 5	Grid 6
16.5 M4	31.4 M4	32.7 M4
Grid 7	Grid 8	Grid 9
21.1 M4	25.3 M4	25.3 M4

Jan. 12-13, Apr 5, July	Report No	FCC ID	
13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

 $0\ dB = 43.5V/m$

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 170 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			\mathbf{W}
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 1:00:42 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_high_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.1 V/m; Power Drift = -0.076 dB

Maximum value of Total (measured) = 48.9 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 41.6 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 171 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${\sf JW}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 25.1 V/m; Power Drift = -0.076 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
40.8 M4	44.2 M4	42.4 M4
Grid 4	Grid 5	Grid 6
33.2 M4	41.6 M4	41.1 M4
Grid 7	Grid 8	Grid 9
18.7 M4	30.8 M4	30.8 M4

Service	REN71UW	Serry® Smartphone mod		172 (342)	
author Data Andrew Becker	Jan. 12-13, Apr 5, July	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U	IJ w	
	13, 2011		L6AREN70U		
				_	

 $0\ dB=44.2V/m$

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Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 10:34:16 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_low_chan_Slide_Open

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 71.8 V/m; Power Drift = 0.131 dB

Maximum value of Total (measured) = 57.5 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 172.7 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 174 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW		
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 71.8 V/m; Power Drift = 0.131 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
151.5 M3	168.7 M3	166.4 M3
Grid 4	Grid 5	Grid 6
154.9 M3	172.7 M3	169.3 M3
Grid 7	Grid 8	Grid 9
154.6 M3	169.6 M3	165.8 M3

lesting Service	REN71UW Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	
	,	,	,	

0 dB = 172.7 V/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 10:40:53 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_mid_chan_Slide_Open

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 84.6 V/m; Power Drift = -0.305 dB

Maximum value of Total (measured) = 65.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 195.3 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 177 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 84.6 V/m; Power Drift = -0.305 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
166.1 M3	190.4 M3	188.5 M3
Grid 4	Grid 5	Grid 6
169.7 M3	195.3 M3	192.2 M3
Grid 7	Grid 8	Grid 9
170.4 M3	192.3 M3	189.1 M3

Services™	REN71UW	Serry® Smartphone mod		178 (342)
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 179 (342)
Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 10:45:44 PM

Test Laboratory: RIM Testing Services HAC_E_GSM850_high_chan_Slide_Open

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 85.3 V/m; Power Drift = -0.041 dB

Maximum value of Total (measured) = 67.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 201.6 V/m

Testing Services	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 180 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW		
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 85.3 V/m; Power Drift = -0.041 dB

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
176.8 M3	198.4 M3	196.1 M3
Grid 4	Grid 5	Grid 6
175.8 M3	201.6 M3	198.6 M3
Grid 7	Grid 8	Grid 9
172.0 M3	196.4 M3	194.2 M3

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
Author Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U		

 $0 dB = \overline{201.6V/m}$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			\mathbf{W}
	13, 2011 L6AREN70UW			\mathbf{W}

Date/Time: 1/12/2011 10:50:20 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM850_high_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 84.0 V/m; Power Drift = 0.049 dB

Maximum value of Total (measured) = 65.9 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 198.4 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 183 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			J W
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 3.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 84.0 V/m; Power Drift = 0.049 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
180.7 M3	191.5 M3	179.3 M3
Grid 4	Grid 5	Grid 6
181.2 M3	198.4 M3	189.4 M3
Grid 7	Grid 8	Grid 9
181.2 M3	198.4 M3	189.6 M3

Testing Services™	REN71UW			184 (342)	
Author Data	Dates of Test	Report No	FCC ID	****	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U		
	13, 2011		L6AREN70U	W	

0 dB = 198.4 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 185 (342)
Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 11:50:16 PM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 72.0 V/m; Power Drift = -0.132 dB

Maximum value of Total (measured) = 57.3 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 55.2 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 72.0 V/m; Power Drift = -0.132 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
47.0 M4	54.1 M4	54.0 M4
Grid 4	Grid 5	Grid 6
47.5 M4	55.2 M4	55.1 M4
Grid 7	Grid 8	Grid 9
46.9 M4	54.3 M4	54.2 M4

Testing Services™	Annex A to Hearing Ai Report for the BlackB REN71UW	id Compatibility RF Emi erry® Smartphone mode		187 (342)
Author Data Andrew Becker	Jan. 12-13, Apr 5, July	Report No RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

 $0\ dB = 55.2 V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 11:56:17 PM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 69.6 V/m; Power Drift = -0.167 dB

Maximum value of Total (measured) = 56.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 54.6 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 69.6 V/m; Power Drift = -0.167 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
43.9 M4	52.8 M4	52.4 M4
Grid 4	Grid 5	Grid 6
45.7 M4	54.6 M4	54.6 M4
Grid 7	Grid 8	Grid 9
45.7 M4	54.3 M4	54.3 M4

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 $0\ dB = 54.6 V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			\mathbf{W}
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 12:00:49 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 78.2 V/m; Power Drift = 0.049 dB

Maximum value of Total (measured) = 63.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 61.3 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
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Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 78.2 V/m; Power Drift = 0.049 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
51.9 M4	60.2 M4	60.1 M4
Grid 4	Grid 5	Grid 6
51.9 M4	61.3 M4	61.3 M4
Grid 7	Grid 8	Grid 9
55.4 M4	60.2 M4	60.1 M4

Testing Services	RENTIOW	id Compatibility RF Em Berry® Smartphone mod	lel RDM71UW/	193 (342)
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 $0\ dB=61.3V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/13/2011 12:06:02 AM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_V_high_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 79.4 V/m; Power Drift = 0.014 dB

Maximum value of Total (measured) = 72.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 69.7 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			

Probe Modulation Factor = 0.960

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 79.4 V/m; Power Drift = 0.014 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
54.1 M4	60.5 M4	57.4 M4
Grid 4	Grid 5	Grid 6
56.3 M4	69.7 M4	60.2 M4
Grid 7	Grid 8	Grid 9
54.6 M4	61.6 M4	60.2 M4

REN71UW				Testing Services™	謝
DM70UW EN70UW		Report No RTS-3640-1102-01B	Jan. 12-13, Apr 5, July 13, 2011	r	Author Data Andrew Becker

 $0\ dB=69.7V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			\mathbf{W}
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Date/Time: 1/12/2011 11:07:21 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 16.0 V/m; Power Drift = 0.004 dB

Maximum value of Total (measured) = 32.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 71.5 V/m

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	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 16.0 V/m; Power Drift = 0.004 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
63.7 M3	64.3 M3	59.4 M3
Grid 4	Grid 5	Grid 6
44.5 M4	58.3 M3	58.3 M3
Grid 7	Grid 8	Grid 9
71.5 M3	84.0 M3	82.4 M3

lesting Services™	Report for the BlackB REN71UW	id Compatibility RF Em erry® Smartphone mod	lel RDM71UW/	199 (342)
thor Data ndrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

0 dB = 84.0 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 11:13:03 PM

Test Laboratory: RIM Testing Services

HAC_E_GSM1900_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 18.5 V/m; Power Drift = -0.287 dB

Maximum value of Total (measured) = 27.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 72.3 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${\sf JW}$
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 18.5 V/m; Power Drift = -0.287 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
63.4 M3	67.0 M3	64.1 M3
Grid 4	Grid 5	Grid 6
42.2 M4	56.0 M3	56.3 M3
Grid 7	Grid 8	Grid 9
62.6 M3	72.3 M3	71.1 M3

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0 dB = 72.3V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

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Test Laboratory: RIM Testing Services

HAC_E_GSM1900_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 14.3 V/m; Power Drift = 0.027 dB

Maximum value of Total (measured) = 27.2 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 59.6 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 14.3 V/m; Power Drift = 0.027 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
64.3 M3	71.2 M3	69.9 M3
Grid 4	Grid 5	Grid 6
36.5 M4	48.6 M3	51.3 M3
Grid 7	Grid 8	Grid 9
48.0 M3	59.6 M3	59.6 M3

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U		
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 $0\;dB=71.2V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

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Test Laboratory: RIM Testing Services

HAC_E_GSM1900_mid_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 18.0 V/m; Power Drift = -0.179 dB

Maximum value of Total (measured) = 28.9 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 64.1 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.61

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 18.0 V/m; Power Drift = -0.179 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
75.6 M3	75.5 M3	61.9 M3
Grid 4	Grid 5	Grid 6
48.1 M3	53.7 M3	53.3 M3
Grid 7	Grid 8	Grid 9
57.4 M3	64.1 M3	61.5 M3

Testing Services™	REN71UW				
Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U		

0 dB = 75.6 V/m

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Author Data	Dates of Test Report No FCC ID			
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
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Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 19.3 V/m; Power Drift = -0.609 dB

Maximum value of Total (measured) = 38.6 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.4 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 19.3 V/m; Power Drift = -0.609 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
27.8 M4	30.9 M4	31.4 M4
Grid 4	Grid 5	Grid 6
17.5 M4	23.7 M4	27.1 M4
Grid 7	Grid 8	Grid 9
29.0 M4	35.2 M4	32.7 M4

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0 dB = 35.2 V/m

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	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 11:34:33 PM

Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.2 V/m; Power Drift = -0.027 dB

Maximum value of Total (measured) = 36.4 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 32.7 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
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Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 22.2 V/m; Power Drift = -0.027 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
28.6 M4	30.3 M4	29.6 M4
Grid 4	Grid 5	Grid 6
18.1 M4	25.1 M4	25.3 M4
Grid 7	Grid 8	Grid 9
27.7 M4	32.7 M4	32.3 M4

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 $0\ dB=32.7V/m$

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Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.9 V/m; Power Drift = 0.082 dB

Maximum value of Total (measured) = 40.1 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 31.6 V/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
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Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 20.9 V/m; Power Drift = 0.082 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
32.4 M4	36.2 M4	35.5 M4
Grid 4	Grid 5	Grid 6
16.5 M4	25.5 M4	26.7 M4
Grid 7	Grid 8	Grid 9
25.9 M4	31.6 M4	31.6 M4

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 $0\ dB=36.2V/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
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Test Laboratory: RIM Testing Services

HAC_E_UMTS_band_II_mid_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1000$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: ER3DV6 - SN2285; ConvF(1, 1, 1); Calibrated: 3/8/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 23.8 V/m; Power Drift = -0.628 dB

Maximum value of Total (measured) = 39.7 V/m

E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 29.7 V/m

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Probe Modulation Factor = 0.900

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 23.8 V/m; Power Drift = -0.628 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
35.7 M4	35.0 M4	29.2 M4
Grid 4	Grid 5	Grid 6
21.7 M4	25.1 M4	25.0 M4
Grid 7	Grid 8	Grid 9
26.2 M4	29.7 M4	28.9 M4

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	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		
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 $0\ dB=35.7V/m$

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_low_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.053 A/m; Power Drift = 0.017 dB

Maximum value of Total (measured) = 0.106 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.222 A/m

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Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.053 A/m; Power Drift = 0.017 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.308 M4	0.222 M4	0.136 M4
Grid 4	Grid 5	Grid 6
0.274 M4	0.195 M4	0.118 M4
Grid 7	Grid 8	Grid 9
0.304 M4	0.214 M4	0.130 M4

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0 dB = 0.308 A/m

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_mid_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.067 A/m; Power Drift = 0.033 dB

Maximum value of Total (measured) = 0.129 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.270 A/m

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Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.067 A/m; Power Drift = 0.033 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.371 M4	0.270 M4	0.176 M4
Grid 4	Grid 5	Grid 6
0.333 M4	0.238 M4	0.151 M4
Grid 7	Grid 8	Grid 9
0.375 M4	0.268 M4	0.160 M4

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0 dB = 0.375 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
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Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.085 A/m; Power Drift = -0.069 dB

Maximum value of Total (measured) = 0.157 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.347 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UV			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.085 A/m; Power Drift = -0.069 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.428 M4	0.319 M4	0.198 M4
Grid 4	Grid 5	Grid 6
0.405 M4	0.308 M4	0.200 M4
Grid 7	Grid 8	Grid 9
0.458 M3	0.347 M4	0.225 M4

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Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U L6AREN70U	
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 $0\ dB=0.458A/m$

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011 RTS-3640-1102-01B L6ARDM70UW L6AREN70UW			

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.084 A/m; Power Drift = -0.045 dB

Maximum value of Total (measured) = 0.134 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.284 A/m

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	13, 2011		LL6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.084 A/m; Power Drift = -0.045 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.392 M4	0.284 M4	0.174 M4
Grid 4	Grid 5	Grid 6
0.390 M4	0.281 M4	0.168 M4
Grid 7	Grid 8	Grid 9
0.379 M4	0.279 M4	0.172 M4

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	13, 2011		LOAKEN/UU	YV

0 dB = 0.392 A/m

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_low_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = 0.024 dB

Maximum value of Total (measured) = 0.100 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.071 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = 0.024 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.098 M4	0.071 M4	0.044 M4
Grid 4	Grid 5	Grid 6
0.085 M4	0.063 M4	0.038 M4
Grid 7	Grid 8	Grid 9
0.095 M4	0.069 M4	0.042 M4

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0 dB = 0.098A/m

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	13, 2011		L6AREN70U	\mathbf{W}

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_mid_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.054 A/m; Power Drift = 0.242 dB

Maximum value of Total (measured) = 0.105 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.076 A/m

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Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.054 A/m; Power Drift = 0.242 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.103 M4	0.076 M4	0.049 M4
Grid 4	Grid 5	Grid 6
0.089 M4	0.067 M4	0.042 M4
Grid 7	Grid 8	Grid 9
0.102 M4	0.074 M4	0.045 M4

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0 dB = 0.103 A/m

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	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 8:45:24 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_high_chan

DUT: BlackBerry Smartphone

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = 0.058 dB

Maximum value of Total (measured) = 0.126 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.094 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = 0.058 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.118 M4	0.090 M4	0.058 M4
Grid 4	Grid 5	Grid 6
0.108 M4	0.083 M4	0.062 M4
Grid 7	Grid 8	Grid 9
0.123 M4	0.094 M4	0.060 M4

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13, 2011		LUAREN/UU	<u> </u>

0 dB = 0.123 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 8:53:19 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_high_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = 0.052 dB

Maximum value of Total (measured) = 0.112 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.080 A/m

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Jan. 12-13, Apr 5, July	RTS-3640-1102-01B		
	Report for the BlackBo REN71UW Dates of Test	Annex A to Hearing Aid Compatibility RF Em Report for the BlackBerry® Smartphone mod REN71UW Dates of Test Jan. 12-13, Apr 5, July RTS-3640-1102-01B	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/REN71UW Dates of Test Jan. 12-13, Apr 5, July RTS-3640-1102-01B FCC ID L6ARDM70U

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = 0.052 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.110 M4	0.080 M4	0.051 M4
Grid 4	Grid 5	Grid 6
0.108 M4	0.078 M4	0.049 M4
Grid 7	Grid 8	Grid 9
0.102 M4	0.075 M4	0.047 M4

v Becker	Dates of Test Long 12, 13, Apr. 5, July	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U	T XX /
	Jan. 12-13, Apr 5, July 13, 2011	K1S-3040-1102-01B	L6AREN70U	

0 dB = 0.110 A/m

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Test Laboratory: RIM Testing Services

HAC_H_GSM1900_low_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.095 A/m; Power Drift = -0.072 dB

Maximum value of Total (measured) = 0.093 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	

Maximum value of peak Total field = 0.240 A/m

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.095 A/m; Power Drift = -0.072 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.256 M2	0.234 M3	0.235 M3
Grid 4	Grid 5	Grid 6
0.180 M3	0.239 M3	0.240 M3
Grid 7	Grid 8	Grid 9
0.165 M3	0.224 M3	0.224 M3

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U	IW		
and our books.	13, 2011	1115 CO 10 1102 VID	L6AREN70U			

0 dB = 0.256 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 9:35:22 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_mid_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.089 A/m; Power Drift = -0.113 dB

Maximum value of Total (measured) = 0.094 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.221 A/m

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	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.089 A/m; Power Drift = -0.113 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.259 M2	0.232 M3	0.219 M3
Grid 4	Grid 5	Grid 6
0.182 M3	0.221 M3	0.221 M3
Grid 7	Grid 8	Grid 9
0.151 M3	0.209 M3	0.209 M3

Service	REN71UW	erry® Smartphone mod		250 (342)
hor Data ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

0 dB = 0.259 A/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 251 (342)
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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM700			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 9:47:45 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_high_chan

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.076 A/m; Power Drift = -0.481 dB

Maximum value of Total (measured) = 0.098 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.190 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${\sf J}{f W}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.076 A/m; Power Drift = -0.481 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.271 M2	0.246 M3	0.190 M3
Grid 4	Grid 5	Grid 6
0.175 M3	0.190 M3	0.190 M3
Grid 7	Grid 8	Grid 9
0.129 M4	0.178 M3	0.178 M3

Testing Services™	Annex A to Hearing A Report for the BlackB REN71UW	id Compatibility RF Em erry® Smartphone mod		Page 253 (342)	
author Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

0 dB = 0.271 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

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Test Laboratory: RIM Testing Services

HAC_H_GSM1900_low_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.096 A/m; Power Drift = 0.026 dB

Maximum value of Total (measured) = 0.099 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.241 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.096 A/m; Power Drift = 0.026 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.275 M2	0.209 M3	0.200 M3
Grid 4	Grid 5	Grid 6
0.226 M3	0.241 M3	0.238 M3
Grid 7	Grid 8	Grid 9
0.202 M3	0.241 M3	0.239 M3

Testi Servi	ing ices™		id Compatibility RF Em erry® Smartphone mod		256 (342)	
uthor Data Andrew Becker		Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

 $0\ dB=0.275A/m$

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Date/Time: 1/12/2011 9:00:01 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_low_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.113 A/m; Power Drift = -0.270 dB

Maximum value of Total (measured) = 0.140 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Maximum value of peak Total field = 0.099 A/m

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.113 A/m; Power Drift = -0.270 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.124 M4	0.109 M4	0.097 M4
Grid 4	Grid 5	Grid 6
0.081 M4	0.098 M4	0.099 M4
Grid 7	Grid 8	Grid 9
0.065 M4	0.087 M4	0.087 M4

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uthor Data Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 0.124 A/m

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_mid_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.097 A/m; Power Drift = -0.054 dB

Maximum value of Total (measured) = 0.129 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.087 A/m

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	13, 2011		LL6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.097 A/m; Power Drift = -0.054 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.114 M4	0.107 M4	0.089 M4
Grid 4	Grid 5	Grid 6
0.077 M4	0.087 M4	0.087 M4
Grid 7	Grid 8	Grid 9
0.054 M4	0.075 M4	0.075 M4

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW Page 262 (342)				
uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U L6AREN70U		

0 dB = 0.114 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_high_chan

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.106 A/m; Power Drift = 0.053 dB

Maximum value of Total (measured) = 0.148 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.092 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM700			
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.106 A/m; Power Drift = 0.053 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.131 M4	0.118 M4	0.096 M4
Grid 4	Grid 5	Grid 6
0.087 M4	0.092 M4	0.092 M4
Grid 7	Grid 8	Grid 9

REN71UW Data Dates of Test	Report No	FCC ID	
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13, 2011		L6AREN70U	W

0 dB = 0.131 A/m

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	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 9:18:49 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_low_chan_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.109 A/m; Power Drift = 0.083 dB

Maximum value of Total (measured) = 0.151 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.099 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	\mathbf{W}

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.109 A/m; Power Drift = 0.083 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.135 M4	0.107 M4	0.090 M4
Grid 4	Grid 5	Grid 6
0.110 M4	0.099 M4	0.096 M4
Grid 7	Grid 8	Grid 9
0.082 M4	0.097 M4	0.096 M4

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Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70UW	

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 824.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.053 A/m; Power Drift = -0.101 dB

Maximum value of Total (measured) = 0.108 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.229 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${\sf JW}$
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Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.053 A/m; Power Drift = -0.101 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.305 M4	0.229 M4	0.140 M4
Grid 4	Grid 5	Grid 6
0.286 M4	0.202 M4	0.118 M4
Grid 7	Grid 8	Grid 9
0.316 M4	0.222 M4	0.133 M4

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0 dB = 0.316 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			\mathbf{W}
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 5:29:58 PM

Test Laboratory: RIM Testing Services HAC_H_GSM850_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 836.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.060 A/m; Power Drift = -0.414 dB

Maximum value of Total (measured) = 0.123 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.255 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			
	13, 2011		LL6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.060 A/m; Power Drift = -0.414 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.359 M4	0.255 M4	0.158 M4
Grid 4	Grid 5	Grid 6
0.319 M4	0.225 M4	0.128 M4
Grid 7	Grid 8	Grid 9
0.354 M4	0.248 M4	0.139 M4

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0 dB = 0.359 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${ m J}{f W}$
	13, 2011		L6AREN70U	W

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Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.076 A/m; Power Drift = -0.119 dB

Maximum value of Total (measured) = 0.148 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.317 A/m

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Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.076 A/m; Power Drift = -0.119 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.399 M4	0.290 M4	0.177 M4
Grid 4	Grid 5	Grid 6
0.382 M4	0.282 M4	0.181 M4
Grid 7	Grid 8	Grid 9
0.432 M4	0.317 M4	0.208 M4

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 $0\ dB=0.432A/m$

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	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 5:40:25 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM850_high_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: GSM 850; Frequency: 848.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.074 A/m; Power Drift = -0.077 dB

Maximum value of Total (measured) = 0.130 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.268 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
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Probe Modulation Factor = 2.87

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.074 A/m; Power Drift = -0.077 dB

Hearing Aid Near-Field Category: M4 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.378 M4	0.268 M4	0.160 M4
Grid 4	Grid 5	Grid 6
0.369 M4	0.262 M4	0.153 M4
Grid 7	Grid 8	Grid 9
0.372 M4	0.268 M4	0.171 M4

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lrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
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0 dB = 0.378A/m

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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 826.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = 0.212 dB

Maximum value of Total (measured) = 0.103 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

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Maximum value of peak Total field = 0.073 A/m

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = 0.212 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.101 M4	0.073 M4	0.045 M4
Grid 4	Grid 5	Grid 6
0.090 M4	0.065 M4	0.038 M4
Grid 7	Grid 8	Grid 9
0.100 M4	0.071 M4	0.043 M4

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0 dB = 0.101 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 836.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = -0.037 dB

Maximum value of Total (measured) = 0.103 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.074 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
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Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.050 A/m; Power Drift = -0.037 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.101 M4	0.074 M4	0.047 M4
Grid 4	Grid 5	Grid 6
0.090 M4	0.065 M4	0.038 M4
Grid 7	Grid 8	Grid 9
0.100 M4	0.070 M4	0.041 M4

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rew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
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0 dB = 0.101 A/m

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.065 A/m; Power Drift = 0.173 dB

Maximum value of Total (measured) = 0.129 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.095 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.065 A/m; Power Drift = 0.173 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.119 M4	0.090 M4	0.056 M4
Grid 4	Grid 5	Grid 6
0.108 M4	0.091 M4	0.060 M4
Grid 7	Grid 8	Grid 9
0.127 M4	0.095 M4	0.057 M4

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0 dB = 0.127 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

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Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_V_high_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD V; Frequency: 846.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.066 A/m; Power Drift = -0.054 dB

Maximum value of Total (measured) = 0.117 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.084 A/m

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	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.980

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.066 A/m; Power Drift = -0.054 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.115 M4	0.084 M4	0.054 M4
Grid 4	Grid 5	Grid 6
0.111 M4	0.080 M4	0.049 M4
Grid 7	Grid 8	Grid 9
0.109 M4	0.079 M4	0.056 M4

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nthor Data Indrew Becker	Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

0 dB = 0.115 A/m

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Test Laboratory: RIM Testing Services

HAC_H_GSM1900_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1850.2 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = -0.029 dB

Maximum value of Total (measured) = 0.066 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.179 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.069 A/m; Power Drift = -0.029 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.168 M3	0.179 M3	0.183 M3
Grid 4	Grid 5	Grid 6
0.137 M4	0.179 M3	0.182 M3
Grid 7	Grid 8	Grid 9
0.179 M3	0.150 M3	0.151 M3

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uthor Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

0 dB = 0.183 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 5:59:28 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.075 A/m; Power Drift = 0.009 dB

Maximum value of Total (measured) = 0.075 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.196 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.075 A/m; Power Drift = 0.009 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.207 M3	0.197 M3	0.196 M3
Grid 4	Grid 5	Grid 6
0.169 M3	0.196 M3	0.195 M3
Grid 7	Grid 8	Grid 9
0.138 M4	0.165 M3	0.164 M3

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ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U	

 $0\ dB=0.207A/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 6:04:30 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1909.8 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.071 A/m; Power Drift = -0.056 dB

Maximum value of Total (measured) = 0.081 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.185 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		LL6AREN70U	W

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.071 A/m; Power Drift = -0.056 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.222 M3	0.200 M3	0.185 M3
Grid 4	Grid 5	Grid 6
0.161 M3	0.185 M3	0.184 M3
Grid 7	Grid 8	Grid 9
0.136 M4	0.163 M3	0.162 M3

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Author Data Andrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

0 dB = 0.222 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 6:11:38 PM

Test Laboratory: RIM Testing Services

HAC_H_GSM1900_mid_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: GSM 1900; Frequency: 1880 MHz; Duty Cycle: 1:8.3

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.074 A/m; Power Drift = 0.034 dB

Maximum value of Total (measured) = 0.081 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.195 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		LL6AREN70U	\mathbf{W}

Probe Modulation Factor = 2.76

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.074 A/m; Power Drift = 0.034 dB

Hearing Aid Near-Field Category: M3 (AWF -5 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.224 M3	0.193 M3	0.188 M3
Grid 4	Grid 5	Grid 6
0.181 M3	0.195 M3	0.191 M3
Grid 7	Grid 8	Grid 9
0.162 M3	0.183 M3	0.179 M3

Data	REN71UW Dates of Test	Report No	FCC ID	
Irew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

 $0\ dB=0.224A/m$

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 1/12/2011 6:32:01 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_low_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.098 A/m; Power Drift = -0.696 dB

Maximum value of Total (measured) = 0.109 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.089 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${\sf JW}$
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.098 A/m; Power Drift = -0.696 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.078 M4	0.091 M4	0.096 M4
Grid 4	Grid 5	Grid 6
0.065 M4	0.089 M4	0.097 M4
Grid 7	Grid 8	Grid 9
0.070 M4	0.081 M4	0.085 M4

Becker	REN71UW Dates of Test Jan. 12-13, Apr 5, July	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U	T XX /
	13, 2011	K15-3040-1102-01B	L6AREN70U	

0 dB = 0.097 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 6:39:09 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_mid_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1880 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.093 A/m; Power Drift = -0.100 dB

Maximum value of Total (measured) = 0.099 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.081 A/m

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.093 A/m; Power Drift = -0.100 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.088 M4	0.082 M4	0.082 M4
Grid 4	Grid 5	Grid 6
0.068 M4	0.081 M4	0.081 M4
Grid 7	Grid 8	Grid 9
0.061 M4	0.068 M4	0.068 M4

REN71UW Dates of Test	Report No	FCC ID	
Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

0 dB = 0.088A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 1/12/2011 7:54:51 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_high_chan_Slide_Open

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1907.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.083 A/m; Power Drift = -0.719 dB

Maximum value of Total (measured) = 0.101 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.081 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.083 A/m; Power Drift = -0.719 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.087 M4	0.091 M4	0.085 M4
Grid 4	Grid 5	Grid 6
0.073 M4	0.070 M4	0.081 M4
Grid 7	Grid 8	Grid 9
0.052 M4	0.059 M4	0.068 M4

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thor Data ndrew Becker	Dates of Test Jan. 12-13, Apr 5, July 13, 2011	Report No RTS-3640-1102-01B	L6ARDM70U		

0 dB = 0.091 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	· · · · ·			
	13, 2011		L6AREN70U	W	

Date/Time: 1/12/2011 8:07:32 PM

Test Laboratory: RIM Testing Services

HAC_H_UMTS_band_II_low_chan_Slide_Open_Telecoil

DUT: BlackBerry Smartphone;

Communication System: WCDMA FDD II; Frequency: 1852.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 1$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

• Probe: H3DV6 - SN6168; ; Calibrated: 3/12/2010

• Sensor-Surface: 0mm (Fix Surface)Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 5/17/2010

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• Measurement SW: DASY4, V4.7 Build 80; Postprocessing SW: SEMCAD, V1.8 Build 186

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (11x11x1): Measurement grid: dx=5mm, dy=5mm

Probe Modulation Factor = 1.00

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.092 A/m; Power Drift = -0.583 dB

Maximum value of Total (measured) = 0.099 A/m

H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.088 A/m

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	J W
	13, 2011		L6AREN70U	W

Probe Modulation Factor = 0.890

Device Reference Point: 0.000, 0.000, -6.30 mm

Reference Value = 0.092 A/m; Power Drift = -0.583 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.078 M4	0.088 M4	0.087 M4
Grid 4	Grid 5	Grid 6
0.076 M4	0.077 M4	0.074 M4
Grid 7	Grid 8	Grid 9
0.068 M4	0.088 M4	0.078 M4

ew Becker J	REN71UW Dates of Test Jan. 12-13, Apr 5, July	Report No RTS-3640-1102-01B	FCC ID L6ARDM70U	
	13, 2011		L6AREN70U	W

 $0\ dB=0.088A/m$

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U L6AREN70U	

Date/Time: 7/13/2011 2:21:52 PM, Date/Time: 7/13/2011 2:17:41 PM, Date/Time:

7/13/2011 2:13:58 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6

MHz, Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 41.678 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
	13, 2011 L6AREN70UW				

Reference Value = 37.282 V/m; Power Drift = 0.09 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
30.749	29.472	30.578
M4	M4	M4
Grid 4	Grid 5	Grid 6
28.216	41.678	42.012
M4	M4	M4
Grid 7	Grid 8	Grid 9
38.267	48.911	48.802
M4	M4	M4

Cursor:

Total = 48.911 V/m E Category: M4 Location: -7, 25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 39.864 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 33.562 V/m; Power Drift = 0.06 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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	13, 2011		L6AREN70U	W	

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
31.856	29.926	27.848
M4	M4	M4
Grid 4	Grid 5	Grid 6
27.079	39.864	40.377
M4	M4	M4
Grid 7	Grid 8	Grid 9
38.410	49.273	49.114
M4	M4	M4

Cursor:

Total = 49.273 V/m E Category: M4

Location: -6.5, 25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 39.071 V/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 30.575 V/m; Power Drift = -0.03 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

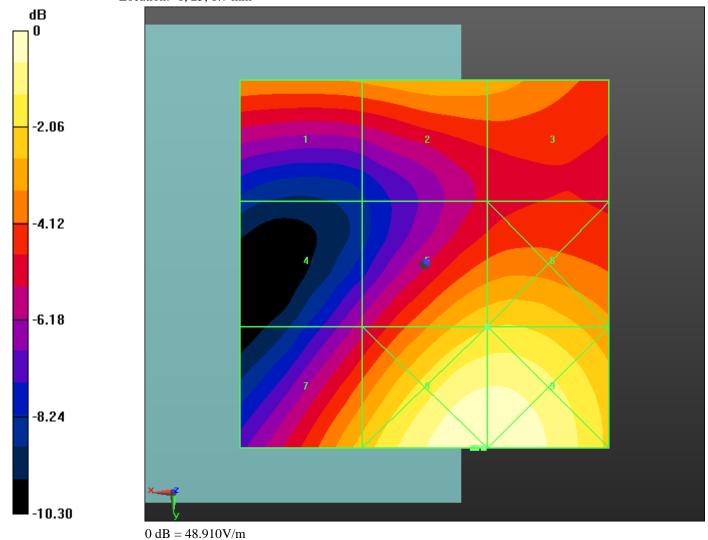
Grid 1	Grid 2	Grid 3
33.790	35.819	34.971
M4	M4	M4
Grid 4	Grid 5	Grid 6
24.671	39.071	39.639
M4	M4	M4
Grid 7	Grid 8	Grid 9
37.662	50.884	50.861
M4	M4	M4

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
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Cursor:

Total = 50.884 V/m E Category: M4

Location: -8, 25, 8.7 mm



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
	13, 2011		L6AREN70U	\mathbf{W}	

Date/Time: 7/13/2011 3:03:15 PM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV_Telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 38.447 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.849 V/m; Power Drift = -0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

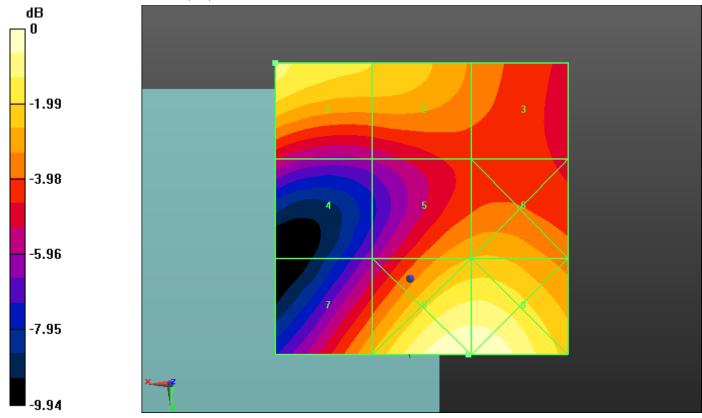
Testing Services™	Annex A to Hearing Aid Report for the BlackBe REN71UW	Page 322 (342)			
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
	13, 2011 L6AREN70UW				

Grid 1	Grid 2	Grid 3
38.447	34.555	29.339
M4	M4	M4
Grid 4	Grid 5	Grid 6
23.802	32.050	32.347
M4	M4	M4
Grid 7	Grid 8	Grid 9
32.173	43.358	43.336
M4	M4	M4

Cursor:

Total = 43.358 V/m E Category: M4

Location: -10, 13, 8.7 mm



0 dB = 43.360 V/m

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW				
Author Data	Dates of Test	Report No	FCC ID		
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW				
	13, 2011 L6AREN70UW				

Date/Time: 7/13/2011 11:47:50 AM, Date/Time: 7/13/2011 11:51:20 AM, Date/Time:

7/13/2011 11:54:40 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV_Slide_Open

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6

MHz, Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 44.597 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70UW	
	13, 2011		L6AREN70U	\mathbf{W}

Reference Value = 39.270 V/m; Power Drift = 0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3	
30.131	30.471	31.777	
M4	M4	M4	
Grid 4	Grid 5	Grid 6	
28.937	44.597	44.971	
M4	M4	M4	
Grid 7	Grid 8	Grid 9	
39.705	51.429	51.363	
M4	M4	M4	

Cursor:

Total = 51.429 V/m E Category: M4

Location: -7.5, 24.5, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 43.894 V/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 37.835 V/m; Power Drift = -0.07 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Peak E-field in V/m

Grid 1	Grid 2	Grid 3
35.966	27.718	29.485
M4	M4	M4
Grid 4	Grid 5	Grid 6
29.467	43.894	44.059
M4	M4	M4
Grid 7	Grid 8	Grid 9
42.576	52.559	52.245
M4	M4	M4

Cursor:

Total = 52.559 V/m E Category: M4

Location: -6, 25, 8.7 mm

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 45.019 V/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.790 V/m; Power Drift = -0.08 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

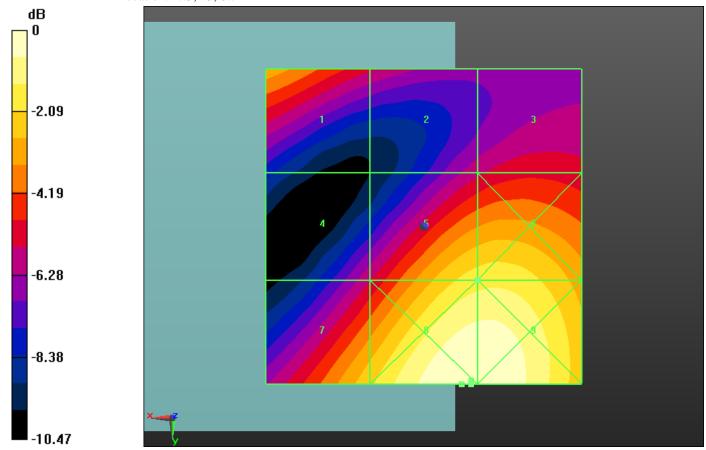
Peak E-field in V/m

Grid 1	Grid 2	Grid 3
38.402	29.092	30.459
M4	M4	M4
Grid 4	Grid 5	Grid 6
28.464	45.019	45.619
M4	M4	M4
Grid 7	Grid 8	Grid 9
42.361	54.962	54.894
M4	M4	M4

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	VV

Total = 54.961 V/m E Category: M4

Location: -7.5, 25, 8.7 mm



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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Date/Time: 7/13/2011 11:58:12 AM

Test Laboratory: RIM Testing Services

HAC RF_E-Field_UMTS_band_IV_Slide_Open_Telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1732.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: ER3DV6 - SN2286; ConvF(1, 1, 1); Calibrated: 1/14/2011

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device E-Field measurement with ER probe/E Scan - ER3D - 2007: 15 mm from Probe Center to the Device Telecoil cent/Hearing Aid Compatibility

Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 43.799 V/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 35.658 V/m; Power Drift = -0.05 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

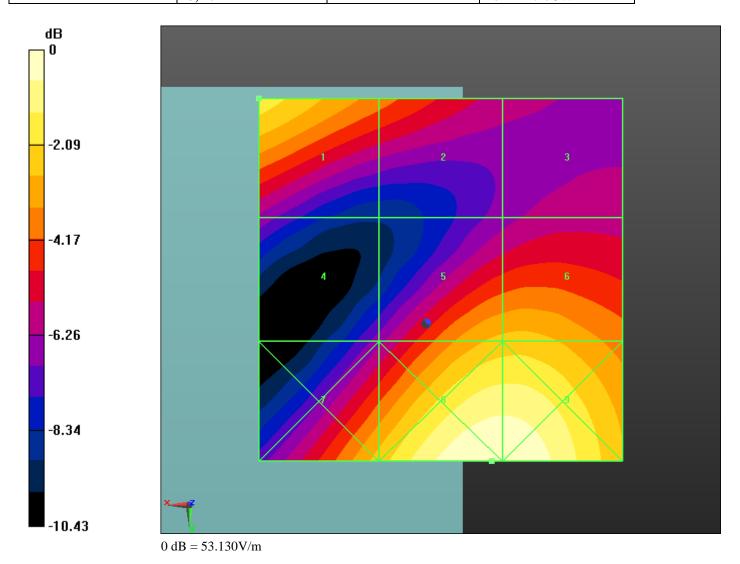
Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Grid 1	Grid 2	Grid 3
43.799	34.378	27.320
M4	M4	M4
Grid 4	Grid 5	Grid 6
25.472	39.671	40.004
M4	M4	M4
Grid 7	Grid 8	Grid 9
40.210	53.132	52.954
M4	M4	M4

Total = 53.132 V/m E Category: M4

Location: -9, 19, 8.7 mm

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Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			
	13, 2011		L6AREN70U	\mathbf{W}



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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 7/13/2011 11:01:42 AM, Date/Time: 7/13/2011 11:05:27 AM, Date/Time:

7/13/2011 11:09:27 AM

Test Laboratory: RIM Testing Services

File Name: HAC RF_H-Field_UMTS_band IV.da52:0

DUT: BlackBerry Smartphone; Type: Sample

Program Name: Program

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6

MHz, Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

DASY4 Configuration:

- Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

- Sensor-Surface: (Fix Surface)

- Electronics: DAE3 Sn472; Calibrated: 3/7/2011

- Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

-; SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.126 A/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/REN71UW			
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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70U	
	13, 2011		L6AREN70U	W

Reference Value = 0.115 A/m; Power Drift = 0.29 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.113	0.115	0.115
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.101	0.113	0.113
M4	M 4	M4
Grid 7	Grid 8	Grid 9
0.126	0.103	0.093
M4	M4	M4

Cursor:

Total = 0.126 A/m H Category: M4

Location: 25, 25, 8.7 mm

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.126 A/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.132 A/m; Power Drift = 0.03 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			
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Andrew Becker	Jan. 12-13, Apr 5, July 13, 2011	RTS-3640-1102-01B	L6ARDM70U	

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.112	0.127	0.127
M4	M4	M 4
Grid 4	Grid 5	Grid 6
0.105	0.126	0.126
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.124	0.108	0.106
M4	M4	M4

Cursor:

Total = 0.127 A/m H Category: M4

Location: -8, -11.5, 8.7 mm

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.138 A/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.148 A/m; Power Drift = -0.04 dB

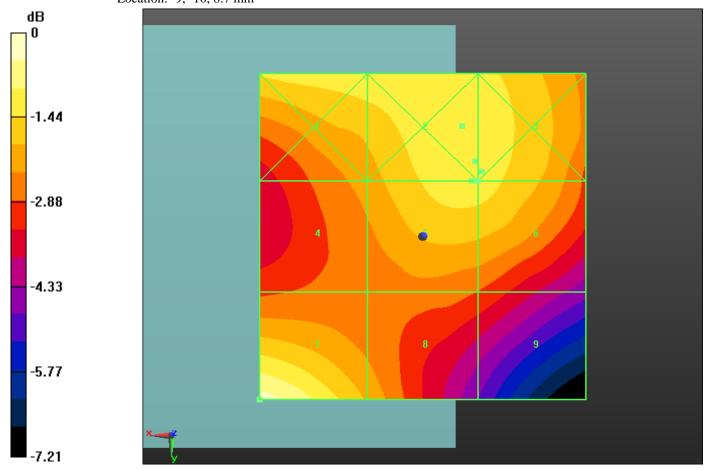
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.123	0.138	0.138
Grid 4 0.115 M4	Grid 5 0.138 M4	Grid 6 0.138 M4
Grid 7	Grid 8	Grid 9
0.126	0.120	0.119
M4	M4	M4

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			J W
	13, 2011		L6AREN70U	W

Total = 0.138 A/m H Category: M4

Location: -9, -10, 8.7 mm



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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			${}^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 7/13/2011 11:13:34 AM

Test Laboratory: RIM Testing Services
HAC RF_H-Field_UMTS_band IV_Telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.137 A/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.147 A/m; Power Drift = 0.03 dB

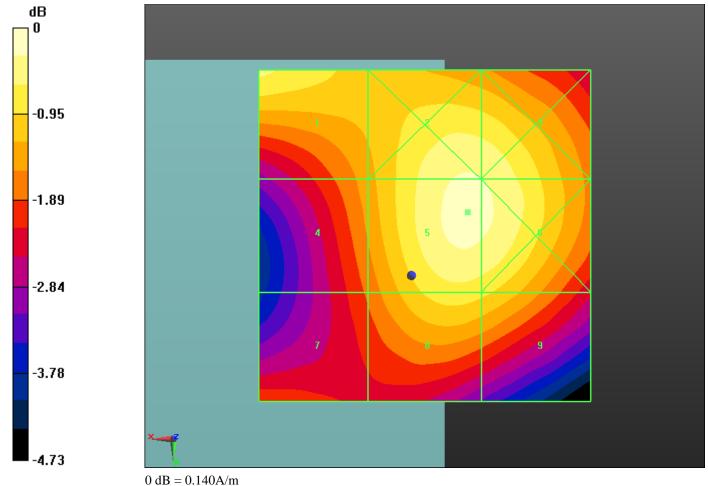
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${\sf J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Grid 1	Grid 2	Grid 3
0.132	0.136	0.135
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.119	0.137	0.136
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.114	0.128	0.127
M4	M4	M4

Total = 0.137 A/mH Category: M4

Location: -8.5, -9.5, 8.7 mm



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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70U			$^{\mathrm{J}}\mathbf{W}$
	13, 2011		L6AREN70U	W

Date/Time: 7/13/2011 11:25:17 AM, Date/Time: 7/13/2011 11:29:01 AM, Date/Time:

7/13/2011 11:32:31 AM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band IV_Slide_Open

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz, Frequency: 1732.6

MHz, Frequency: 1752.6 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

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Andrew Becker	Jan. 12-13, Apr 5, July RTS-3640-1102-01B L6ARDM70UW			${ m J}{f W}$
	13, 2011		L6AREN70U	\mathbf{W}

Reference Value = 0.110 A/m; Power Drift = 0.13 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.098	0.102	0.101
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.105	0.101	0.100
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.137	0.116	0.087
M4	M4	M4

Cursor:

Total = 0.137 A/mH Category: M4

Location: 25, 25, 8.7 mm

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.112 A/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.121 A/m; Power Drift = -0.01 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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	13, 2011		L6AREN70U	W

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.102	0.112	0.111
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.103	0.111	0.111
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.130	0.108	0.094
M4	M4	M4

Cursor:

Total = 0.130 A/m H Category: M4

Location: 25, 25, 8.7 mm

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2/Hearing Aid

Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.121 A/m

Probe Modulation Factor = 0.970 Device Reference Point: 0, 0, -6.3 mm

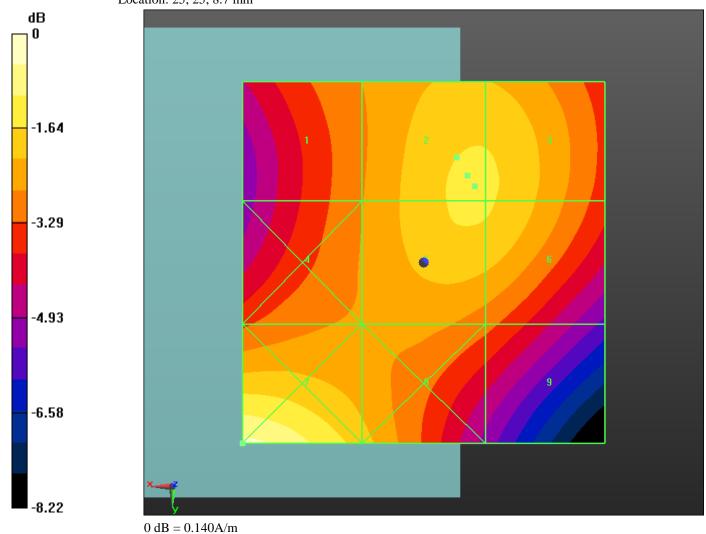
Reference Value = 0.131 A/m; Power Drift = -0.0024 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Grid 1	Grid 2	Grid 3
0.108	0.121	0.121
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.109	0.121	0.121
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.135	0.117	0.105
M4	M4	M4

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Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70UW	
	13, 2011		L6AREN70U	\mathbf{W}

Total = 0.135 A/m H Category: M4 Location: 25, 25, 8.7 mm



Testing Services™	Annex A to Hearing Aid Compatibility RF Emissions Test Report for the BlackBerry® Smartphone model RDM71UW/ REN71UW			Page 340 (342)
Author Data	Dates of Test	Report No	FCC ID	
Andrew Becker	Jan. 12-13, Apr 5, July	RTS-3640-1102-01B	L6ARDM70UW	
	13, 2011		L6AREN70U	\mathbf{W}

Date/Time: 7/13/2011 11:38:03 AM

Test Laboratory: RIM Testing Services

HAC RF_H-Field_UMTS_band IV_Slide_Open_Telecoil

DUT: BlackBerry Smartphone; Type: Sample

Communication System: WCDMA FDD IV; Frequency: 1712.4 MHz; Duty Cycle: 1:1

Medium parameters used: $\sigma = 0$ mho/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

DASY4 Configuration:

• Probe: H3DV6 - SN6105; ; Calibrated: 11/18/2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE3 Sn472; Calibrated: 3/7/2011

• Phantom: HAC RF Test Arch with AMCC; Type: SD HAC P01 BA;

• ; SEMCAD X Version 14.4.4 (2829)

Device H-Field meausrement with H3DV6 probe/H Scan - H3DV6 - 2007: 15 mm from Probe Center to the Device 2 2 2/Hearing Aid Compatibility Test

(101x101x1): Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.102 A/m

Probe Modulation Factor = 0.970

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.111 A/m; Power Drift = -0.04 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

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Grid 1	Grid 2	Grid 3
0.099	0.101	0.099
M4	M4	M4
Grid 4	Grid 5	Grid 6
0.099	0.102	0.100
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.111	0.102	0.096
M4	M4	M4

Total = 0.111 A/m H Category: M4

Location: 23, 13, 8.7 mm

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